

equivalent current opain \$\Delta \text{TD} = \copm
\$\Delta \text{vin}\$

Vaut

The Parameters for The equivalent small frequency what

In large signal assuming level 1 equations
analysis, De simulation

Voll = VDD - ID RD between to saturated

| starting | Imsalunction

VgS = Vim VDS = Vout

VaI = VOO-IDRD

The transistors enters in the Triods
when Vas-Vile > Vout
with vout
as reper

To make sure the transistratays the longuest In saturation, we have to make sure the gain is the lighest.

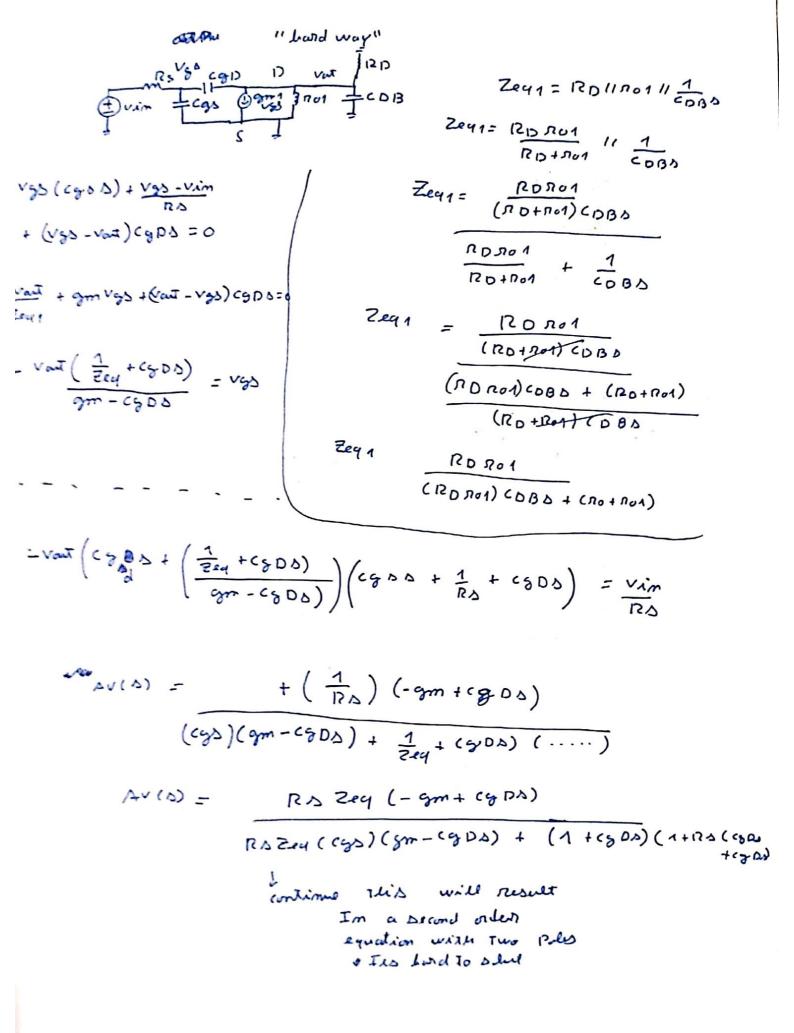
DE THE repult The gain
Becames not linear, creates
a lat of distortion

In The pane Modern Process

ID varies mat im a a quadratic way with changes In vim, and its defendencys in Brocess parameters are mot as linear as They are in level 1 cmas madees

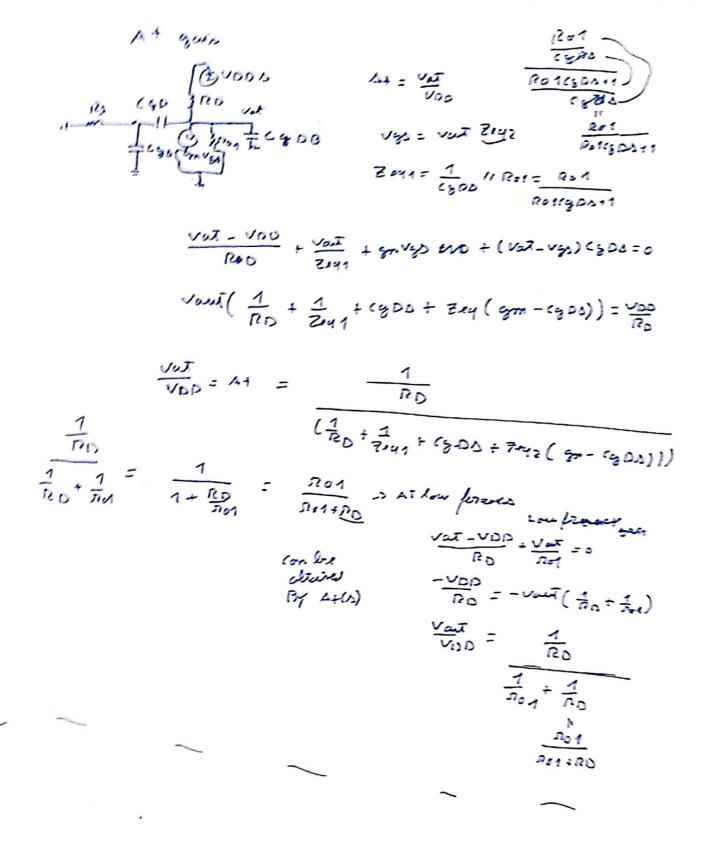
resistable common source stay

equivalent aircust



$$\frac{RS 11 \frac{1}{c_8^2 D} = \frac{RS}{RS c_800 + 1}}{RS c_800 + 1}$$

$$\frac{RS (SDS + RS c_800+1)}{RS (SDS + 1) (SDS}$$



$$\frac{R_{S} - q_{SD}}{R_{S} - q_{SD}} = \frac{1}{3} \frac{1}{3} \frac{1}{2} \frac{1}{2}$$